

MT29F3T08EUHBBM4-3RES:B TR

MT29F3T08EUHBBM4-3RES:B TR Information

Contraction to the second seco	 MT29F3T08EUHBBM4-3RES:B TR Micron Technology Inc. Integrated Circuits (ICs) Memory IC FLASH 3TBIT 333MHZ 132LBGA - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MT29F3T08EUHBBM4-3RES:B TR Specifications

Manufacturer Part Number	MT29F3T08EUHBBM4-3RES:B TR
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	-
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	3Tb (384G x 8)
Memory Interface	Parallel
Clock Frequency	333MHz
Write Cycle Time - Word, Page	-
Access Time	-
Voltage - Supply	2.5 V ~ 3.6 V
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

MT29F3T08EUHBBM4-3RES:B TR Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MT29F3T08EUHBBM4-3RES:B TR Payment Methods





If you have any question about MT29F3T08EUHBBM4-3RES:B TR, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com